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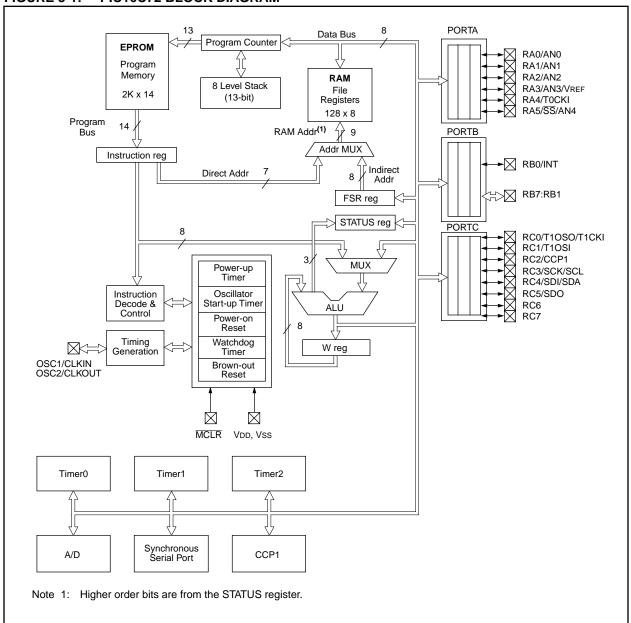
What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	20MHz
Connectivity	I <sup>2</sup> C, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	22
Program Memory Size	14KB (8K x 14)
Program Memory Type	ОТР
EEPROM Size	-
RAM Size	368 x 8
Voltage - Supply (Vcc/Vdd)	4V ~ 6V
Data Converters	A/D 5x8b
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Through Hole
Package / Case	28-DIP (0.300", 7.62mm)
Supplier Device Package	28-SPDIP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c76-20-sp

FIGURE 3-1: PIC16C72 BLOCK DIAGRAM



### 5.7 Parallel Slave Port

Applicable Devices 72 | 73 | 73 | 74 | 74 | 76 | 77

PORTD operates as an 8-bit wide Parallel Slave Port, or microprocessor port when control bit PSPMODE (TRISE<4>) is set. In slave mode it is asynchronously readable and writable by the external world through  $\overline{RD}$  control input pin RE0/ $\overline{RD}$ /AN5 and  $\overline{WR}$  control input pin RE1/ $\overline{WR}$ /AN6.

It can directly interface to an 8-bit microprocessor data bus. The external microprocessor can read or write the PORTD latch as an 8-bit latch. Setting bit PSPMODE enables port pin RE0/ $\overline{RD}$ /AN5 to be the  $\overline{RD}$  input, RE1/ $\overline{WR}$ /AN6 to be the  $\overline{WR}$  input and RE2/ $\overline{CS}$ /AN7 to be the  $\overline{CS}$  (chip select) input. For this functionality, the corresponding data direction bits of the TRISE register (TRISE<2:0>) must be configured as inputs (set) and the A/D port configuration bits PCFG2:PCFG0 (ADCON1<2:0>) must be set, which will configure pins RE2:RE0 as digital I/O.

There are actually two 8-bit latches, one for data-out (from the PIC16/17) and one for data input. The user writes 8-bit data to PORTD data latch and reads data from the port pin latch (note that they have the same address). In this mode, the TRISD register is ignored, since the microprocessor is controlling the direction of data flow.

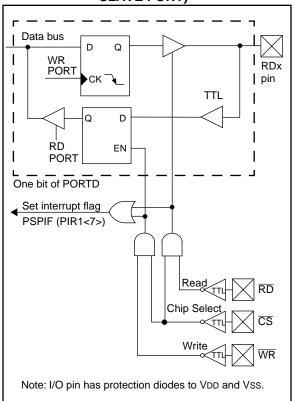
A write to the PSP occurs when both the  $\overline{\text{CS}}$  and  $\overline{\text{WR}}$  lines are first detected low. When either the  $\overline{\text{CS}}$  or  $\overline{\text{WR}}$  lines become high (level triggered), then the Input Buffer Full status flag bit IBF (TRISE<7>) is set on the Q4 clock cycle, following the next Q2 cycle, to signal the write is complete (Figure 5-12). The interrupt flag bit PSPIF (PIR1<7>) is also set on the same Q4 clock cycle. IBF can only be cleared by reading the PORTD input latch. The input Buffer Overflow status flag bit IBOV (TRISE<5>) is set if a second write to the Parallel Slave Port is attempted when the previous byte has not been read out of the buffer.

A read from the PSP occurs when both the  $\overline{\text{CS}}$  and  $\overline{\text{RD}}$  lines are first detected low. The Output Buffer Full status flag bit OBF (TRISE<6>) is cleared immediately (Figure 5-13) indicating that the PORTD latch is waiting to be read by the external bus. When either the  $\overline{\text{CS}}$  or  $\overline{\text{RD}}$  pin becomes high (level triggered), the interrupt flag bit PSPIF is set on the Q4 clock cycle, following the next Q2 cycle, indicating that the read is complete. OBF remains low until data is written to PORTD by the user firmware.

When not in Parallel Slave Port mode, the IBF and OBF bits are held clear. However, if flag bit IBOV was previously set, it must be cleared in firmware.

An interrupt is generated and latched into flag bit PSPIF when a read or write operation is completed. PSPIF must be cleared by the user in firmware and the interrupt can be disabled by clearing the interrupt enable bit PSPIE (PIE1<7>).

FIGURE 5-11: PORTD AND PORTE BLOCK DIAGRAM (PARALLEL SLAVE PORT)



### FIGURE 11-8: SSPCON: SYNC SERIAL PORT CONTROL REGISTER (ADDRESS 14h)(PIC16C76/77)

R/W-0 R/W-0 R/W-0 R/W-0 R/W-0 R/W-0 R/W-0 R/W-0 WCOL **SSPOV SSPEN CKP** SSPM3 SSPM2 SSPM1 SSPM0 R = Readable bit W = Writable bit bit7 bit0 U = Unimplemented bit, read as '0' - n =Value at POR reset

bit 7: WCOL: Write Collision Detect bit

1 = The SSPBUF register is written while it is still transmitting the previous word (must be cleared in software)

0 = No collision

bit 6: SSPOV: Receive Overflow Indicator bit

#### In SPI mode

1 = A new byte is received while the SSPBUF register is still holding the previous data. In case of overflow, the data in SSPSR is lost. Overflow can only occur in slave mode. The user must read the SSPBUF, even if only transmitting data, to avoid setting overflow. In master mode the overflow bit is not set since each new reception (and transmission) is initiated by writing to the SSPBUF register.

0 = No overflow

#### In I<sup>2</sup>C mode

1 = A byte is received while the SSPBUF register is still holding the previous byte. SSPOV is a "don't care" in transmit mode. SSPOV must be cleared in software in either mode.

0 = No overflow

bit 5: SSPEN: Synchronous Serial Port Enable bit

#### In SPI mode

- 1 = Enables serial port and configures SCK, SDO, and SDI as serial port pins
- 0 = Disables serial port and configures these pins as I/O port pins

#### In I<sup>2</sup>C mode

- 1 = Enables the serial port and configures the SDA and SCL pins as serial port pins
- 0 = Disables serial port and configures these pins as I/O port pins

In both modes, when enabled, these pins must be properly configured as input or output.

bit 4: CKP: Clock Polarity Select bit

### In SPI mode

- 1 = Idle state for clock is a high level
- 0 = Idle state for clock is a low level

#### In I<sup>2</sup>C mode

#### SCK release control

- 1 = Enable clock
- 0 = Holds clock low (clock stretch) (Used to ensure data setup time)

### bit 3-0: SSPM3:SSPM0: Synchronous Serial Port Mode Select bits

- 0000 = SPI master mode, clock = Fosc/4
- 0001 = SPI master mode, clock = Fosc/16
- 0010 = SPI master mode, clock = Fosc/64
- 0011 = SPI master mode, clock = TMR2 output/2
- 0100 = SPI slave mode, clock = SCK pin.  $\overline{SS}$  pin control enabled.
- 0101 = SPI slave mode, clock = SCK pin. SS pin control disabled. SS can be used as I/O pin
- $0110 = I^2C$  slave mode, 7-bit address
- $0111 = I^2C$  slave mode, 10-bit address
- $1011 = I^2C$  firmware controlled master mode (slave idle)
- $1110 = I^2C$  slave mode, 7-bit address with start and stop bit interrupts enabled
- $1111 = I^2C$  slave mode, 10-bit address with start and stop bit interrupts enabled

# 13.0 ANALOG-TO-DIGITAL CONVERTER (A/D) MODULE

Applicable Devices 72 73 73 A 74 74 A 76 77

The analog-to-digital (A/D) converter module has five inputs for the PIC16C72/73/73A/76, and eight for the PIC16C74/74A/77.

The A/D allows conversion of an analog input signal to a corresponding 8-bit digital number (refer to Application Note AN546 for use of A/D Converter). The output of the sample and hold is the input into the converter, which generates the result via successive approximation. The analog reference voltage is software selectable to either the device's positive supply voltage (VDD) or the voltage level on the RA3/AN3/VREF pin.

The A/D converter has a unique feature of being able to operate while the device is in SLEEP mode. To operate in sleep, the A/D conversion clock must be derived from the A/D's internal RC oscillator.

The A/D module has three registers. These registers are:

- A/D Result Register (ADRES)
- A/D Control Register 0 (ADCON0)
- A/D Control Register 1 (ADCON1)

The ADCON0 register, shown in Figure 13-1, controls the operation of the A/D module. The ADCON1 register, shown in Figure 13-2, configures the functions of the port pins. The port pins can be configured as analog inputs (RA3 can also be a voltage reference) or as digital I/O.

### FIGURE 13-1: ADCON0 REGISTER (ADDRESS 1Fh)

R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	U-0	R/W-0				
ADCS1	ADCS0	CHS2	CHS1	CHS0	GO/DONE		ADON	R = Readable bit			
bit7	bit0 W = Writable bit U = Unimplemented read as '0' - n = Value at POR re										
bit 7-6:	00 = Fose 01 = Fose 10 = Fose	C/2 C/8 C/32			Select bits	r)					
bit 5-3:	11 = FRC (clock derived from an internal RC oscillator)  3: CHS2:CHS0: Analog Channel Select bits  000 = channel 0, (RA0/AN0)  001 = channel 1, (RA1/AN1)  010 = channel 2, (RA2/AN2)  011 = channel 3, (RA3/AN3)  100 = channel 4, (RA5/AN4)  101 = channel 5, (RE0/AN5) <sup>(1)</sup> 110 = channel 6, (RE1/AN6) <sup>(1)</sup> 111 = channel 7, (RE2/AN7) <sup>(1)</sup>										
bit 2:	GO/DON	E: A/D Co	nversion S	Status bit							
		onversion onversion			this bit starts bit is automat			are when the A/D conversion			
bit 1:	Unimpler	mented: F	Read as '0'								
bit 0:	<b>ADON</b> : AA 1 = A/D C 0 = A/D C	onverter r	nodule is o								

### 13.1 A/D Acquisition Requirements

Applicable Devices 72 | 73 | 73 | 74 | 74 | 76 | 77 |

For the A/D converter to meet its specified accuracy, the charge holding capacitor (CHOLD) must be allowed to fully charge to the input channel voltage level. The analog input model is shown in Figure 13-4. The source impedance (Rs) and the internal sampling switch (Rss) impedance directly affect the time required to charge the capacitor CHOLD. The sampling switch (Rss) impedance varies over the device voltage (VDD), Figure 13-4. The source impedance affects the offset voltage at the analog input (due to pin leakage current). The maximum recommended impedance for analog sources is 10  $k\Omega$ . After the analog input channel is selected (changed) this acquisition must be done before the conversion can be started.

To calculate the minimum acquisition time, Equation 13-1 may be used. This equation calculates the acquisition time to within 1/2 LSb error is used (512 steps for the A/D). The 1/2 LSb error is the maximum error allowed for the A/D to meet its specified accuracy.

# EQUATION 13-1: A/D MINIMUM CHARGING TIME

 $VHOLD = (VREF - (VREF/512)) \bullet (1 - e^{(-TCAP/CHOLD(RIC + RSS + RS))})$ 

Given: VHOLD = (VREF/512), for 1/2 LSb resolution

The above equation reduces to:

 $TCAP = -(51.2 pF)(1 k\Omega + Rss + Rs) ln(1/511)$ 

Example 13-1 shows the calculation of the minimum required acquisition time TACQ. This calculation is based on the following system assumptions.

CHOLD = 51.2 pF

 $Rs = 10 k\Omega$ 

1/2 LSb error

 $VDD = 5V \rightarrow Rss = 7 \text{ k}\Omega$ 

Temp (application system max.) = 50°C

VHOLD = 0 @ t = 0

- Note 1: The reference voltage (VREF) has no effect on the equation, since it cancels itself out.
- **Note 2:** The charge holding capacitor (CHOLD) is not discharged after each conversion.
- Note 3: The maximum recommended impedance for analog sources is 10 k $\Omega$ . This is required to meet the pin leakage specification.
- Note 4: After a conversion has completed, a 2.0TAD delay must complete before acquisition can begin again. During this time the holding capacitor is not connected to the selected A/D input channel.

# EXAMPLE 13-1: CALCULATING THE MINIMUM REQUIRED ACQUISITION TIME

TACQ = Amplifier Settling Time +

Holding Capacitor Charging Time +

Temperature Coefficient

TACQ =  $5 \mu s + TCAP + [(Temp - 25^{\circ}C)(0.05 \mu s/^{\circ}C)]$ 

TCAP = -CHOLD (RIC + RSS + RS) In(1/511)

-51.2 pF (1 kΩ + 7 kΩ + 10 kΩ) ln(0.0020)

-51.2 pF (18 kΩ) ln(0.0020)

-0.921 μs (-6.2364)

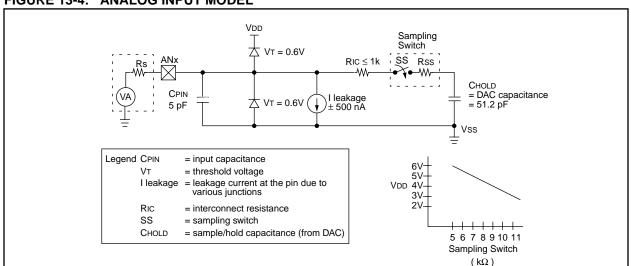
5.747 μs

TACQ =  $5 \mu s + 5.747 \mu s + [(50^{\circ}C - 25^{\circ}C)(0.05 \mu s/^{\circ}C)]$ 

 $10.747 \,\mu s + 1.25 \,\mu s$ 

 $11.997 \mu s$ 

### FIGURE 13-4: ANALOG INPUT MODEL



# 13.4.1 FASTER CONVERSION - LOWER RESOLUTION TRADE-OFF

Not all applications require a result with 8-bits of resolution, but may instead require a faster conversion time. The A/D module allows users to make the trade-off of conversion speed to resolution. Regardless of the resolution required, the acquisition time is the same. To speed up the conversion, the clock source of the A/D module may be switched so that the TAD time violates the minimum specified time (see the applicable electrical specification). Once the TAD time violates the minimum specified time, all the following A/D result bits are not valid (see A/D Conversion Timing in the Electrical Specifications section.) The clock sources may only be switched between the three oscillator versions (cannot be switched from/to RC). The equation to determine the time before the oscillator can be switched is as follows:

Conversion time =  $2TAD + N \cdot TAD + (8 - N)(2TOSC)$ Where: N = number of bits of resolution required. Since the TAD is based from the device oscillator, the user must use some method (a timer, software loop, etc.) to determine when the A/D oscillator may be changed. Example 13-3 shows a comparison of time required for a conversion with 4-bits of resolution, versus the 8-bit resolution conversion. The example is for devices operating at 20 MHz and 16 MHz (The A/D clock is programmed for 32Tosc), and assumes that immediately after 6TAD, the A/D clock is programmed for 2Tosc.

The 2Tosc violates the minimum TAD time since the last 4-bits will not be converted to correct values.

### **EXAMPLE 13-3: 4-BIT vs. 8-BIT CONVERSION TIMES**

	- (m. )(1)	Reso	lution
	Freq. (MHz) <sup>(1)</sup>	4-bit	8-bit
TAD	20	1.6 μs	1.6 µs
	16	2.0 μs	2.0 μs
Tosc	20	50 ns	50 ns
	16	62.5 ns	62.5 ns
2TAD + N • TAD + (8 - N)(2TOSC)	20	10 μs	16 μs
	16	12.5 μs	20 μs

Note 1: PIC16C7X devices have a minimum TAD time of 1.6 µs.

# 14.2.3 EXTERNAL CRYSTAL OSCILLATOR CIRCUIT

Either a prepackaged oscillator can be used or a simple oscillator circuit with TTL gates can be built. Prepackaged oscillators provide a wide operating range and better stability. A well-designed crystal oscillator will provide good performance with TTL gates. Two types of crystal oscillator circuits can be used; one with series resonance, or one with parallel resonance.

Figure 14-5 shows implementation of a parallel resonant oscillator circuit. The circuit is designed to use the fundamental frequency of the crystal. The 74AS04 inverter performs the 180-degree phase shift that a parallel oscillator requires. The 4.7 k $\Omega$  resistor provides the negative feedback for stability. The 10 k $\Omega$  potentiometer biases the 74AS04 in the linear region. This could be used for external oscillator designs.

FIGURE 14-5: EXTERNAL PARALLEL RESONANT CRYSTAL OSCILLATOR CIRCUIT

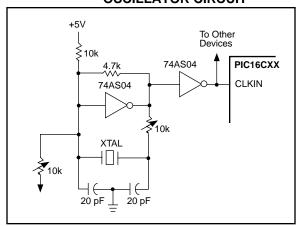
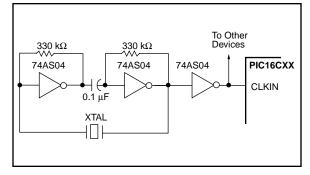


Figure 14-6 shows a series resonant oscillator circuit. This circuit is also designed to use the fundamental frequency of the crystal. The inverter performs a 180-degree phase shift in a series resonant oscillator circuit. The 330 k $\Omega$  resistors provide the negative feedback to bias the inverters in their linear region.

FIGURE 14-6: EXTERNAL SERIES
RESONANT CRYSTAL
OSCILLATOR CIRCUIT



#### 14.2.4 RC OSCILLATOR

For timing insensitive applications the "RC" device option offers additional cost savings. The RC oscillator frequency is a function of the supply voltage, the resistor (Rext) and capacitor (Cext) values, and the operating temperature. In addition to this, the oscillator frequency will vary from unit to unit due to normal process parameter variation. Furthermore, the difference in lead frame capacitance between package types will also affect the oscillation frequency, especially for low Cext values. The user also needs to take into account variation due to tolerance of external R and C components used. Figure 14-7 shows how the R/C combination is connected to the PIC16CXX. For Rext values below 2.2 k $\Omega$ , the oscillator operation may become unstable, or stop completely. For very high Rext values (e.g. 1 M $\Omega$ ), the oscillator becomes sensitive to noise, humidity and leakage. Thus, we recommend to keep Rext between 3 k $\Omega$  and 100 k $\Omega$ .

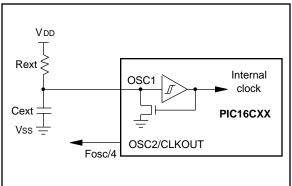
Although the oscillator will operate with no external capacitor (Cext = 0 pF), we recommend using values above 20 pF for noise and stability reasons. With no or small external capacitance, the oscillation frequency can vary dramatically due to changes in external capacitances, such as PCB trace capacitance or package lead frame capacitance.

See characterization data for desired device for RC frequency variation from part to part due to normal process variation. The variation is larger for larger R (since leakage current variation will affect RC frequency more for large R) and for smaller C (since variation of input capacitance will affect RC frequency more).

See characterization data for desired device for variation of oscillator frequency due to VDD for given Rext/ Cext values as well as frequency variation due to operating temperature for given R, C, and VDD values.

The oscillator frequency, divided by 4, is available on the OSC2/CLKOUT pin, and can be used for test purposes or to synchronize other logic (see Figure 3-4 for waveform).

FIGURE 14-7: RC OSCILLATOR MODE



#### 14.4.5 TIME-OUT SEQUENCE

On power-up the time-out sequence is as follows: First PWRT time-out is invoked after the POR time delay has expired. Then OST is activated. The total time-out will vary based on oscillator configuration and the status of the PWRT. For example, in RC mode with the PWRT disabled, there will be no time-out at all. Figure 14-10, Figure 14-11, and Figure 14-12 depict time-out sequences on power-up.

Since the time-outs occur from the POR pulse, if  $\overline{MCLR}$  is kept low long enough, the time-outs will expire. Then bringing  $\overline{MCLR}$  high will begin execution immediately (Figure 14-11). This is useful for testing purposes or to synchronize more than one PIC16CXX device operating in parallel.

Table 14-7 shows the reset conditions for some special function registers, while Table 14-8 shows the reset conditions for all the registers.

# 14.4.6 POWER CONTROL/STATUS REGISTER (PCON)

Applicable Devices 72 73 73 A 74 74 A 76 77

The Power Control/Status Register, PCON has up to two bits, depending upon the device. Bit0 is not implemented on the PIC16C73 or PIC16C74.

Bit0 is Brown-out Reset Status bit,  $\overline{BOR}$ . Bit  $\overline{BOR}$  is unknown on a Power-on Reset. It must then be set by the user and checked on subsequent resets to see if bit  $\overline{BOR}$  cleared, indicating a BOR occurred. The  $\overline{BOR}$  bit is a "Don't Care" bit and is not necessarily predictable if the Brown-out Reset circuitry is disabled (by clearing bit BODEN in the Configuration Word).

Bit1 is POR (Power-on Reset Status bit). It is cleared on a Power-on Reset and unaffected otherwise. The user must set this bit following a Power-on Reset.

TABLE 14-3: TIME-OUT IN VARIOUS SITUATIONS, PIC16C73/74

Oscillator Configuration	Powe	Wake-up from SLEEP	
	PWRTE = 1	PWRTE = 0	
XT, HS, LP	72 ms + 1024Tosc	1024Tosc	1024 Tosc
RC	72 ms	_	_

TABLE 14-4: TIME-OUT IN VARIOUS SITUATIONS, PIC16C72/73A/74A/76/77

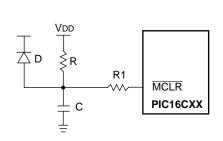
Oscillator Configuration	Power	r-up	Brown-out	Wake-up from SLEEP
	PWRTE = 0	PWRTE = 1	Brown-out	
XT, HS, LP	72 ms + 1024Tosc 1024Tosc		72 ms + 1024Tosc	1024Tosc
RC	72 ms	_	72 ms	_

TABLE 14-5: STATUS BITS AND THEIR SIGNIFICANCE, PIC16C73/74

POR	TO	PD	
0	1	1	Power-on Reset
0	0	х	Illegal, TO is set on POR
0	x	0	Illegal, PD is set on POR
1	0	1	WDT Reset
1	0	0	WDT Wake-up
1	u	u	MCLR Reset during normal operation
1	1	0	MCLR Reset during SLEEP or interrupt wake-up from SLEEP

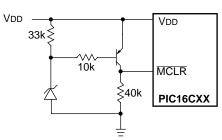
Legend: u = unchanged, x = unknown

### FIGURE 14-13: EXTERNAL POWER-ON RESET CIRCUIT (FOR SLOW VDD POWER-UP)



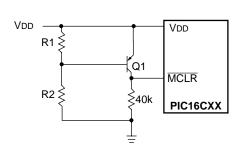
- Note 1: External Power-on Reset circuit is required only if VDD power-up slope is too slow. The diode D helps discharge the capacitor quickly when VDD powers down.
  - 2:  $R < 40 \text{ k}\Omega$  is recommended to make sure that voltage drop across R does not violate the device's electrical specification.
  - 3:  $R1 = 100\Omega$  to 1 k $\Omega$  will limit any current flowing into  $\overline{MCLR}$  from external capacitor C in the event of  $\overline{MCLR}$ /VPP pin breakdown due to Electrostatic Discharge (ESD) or Electrical Overstress (EOS).

# FIGURE 14-14: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 1



- Note 1: This circuit will activate reset when VDD goes below (Vz + 0.7V) where Vz = Zener voltage.
  - 2: Internal brown-out detection on the PIC16C72/73A/74A/76/77 should be disabled when using this circuit.
  - 3: Resistors should be adjusted for the characteristics of the transistor.

# FIGURE 14-15: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 2



Note 1: This brown-out circuit is less expensive, albeit less accurate. Transistor Q1 turns off when VDD is below a certain level such that:

$$VDD \bullet \frac{R1}{R1 + R2} = 0.7V$$

- 2: Internal brown-out detection on the PIC16C72/73A/74A/76/77 should be disabled when using this circuit.
- 3: Resistors should be adjusted for the characteristics of the transistor.

BTFSS	Bit Test 1	f, Skip if S	Set		CALL	Call Sul	oroutine				
Syntax:	[ <i>label</i> ] B1	ΓFSS f,b			Syntax:	[ label ]	CALL I	<b>(</b>			
Operands:	$0 \le f \le 12$	<del></del>			Operands:	$0 \le k \le 2$	$0 \leq k \leq 2047$				
	$0 \le b < 7$				Operation:	(PC)+ 1→ TOS,					
Operation:	skip if (f<	(b>) = 1					$k \rightarrow PC < 10:0>$ ,				
Status Affected:	None					•	$(PCLATH \mathord{<} 4:3\mathord{>}) \to PC \mathord{<} 12:11\mathord{>}$				
Encoding:	01	11bb	bfff	ffff	Status Affected:	None	1				
Description:		register 'f' i		he next	Encoding:	10	0kkk	kkkk	kkkk		
	If bit 'b' is discarded	and a NOI	e next instr	SALITISTI UCTION 13	Description:	Call Subroutine. First, return address (PC+1) is pushed onto the stack. The eleven bit immediate address is loaded into PC bits <10:0>. The upper bits of					
Words:	1						e loaded fi ycle instru	rom PĊĹAī ction.	Γ <b>H</b> . CALL		
Cycles:	1(2)				Words:	1	,				
Q Cycle Activity:	Q1	Q2	Q3	Q4	Cycles:	2					
	Decode	Read register 'f'	Process data	No- Operation	Q Cycle Activity:	Q1	Q2	Q3	Q4		
If Skip:	(2nd Cyc	cle)			1st Cycle	Decode	Read literal 'k',	Process data	Write to PC		
·	Q1	Q2	Q3	Q4			Push PC to Stack	data			
	No- Operation	No- Operation	No- Operation	No- Operation	2nd Cycle	No- Operation	No- Operation	No- Operation	No- Operation		
Example	HERE FALSE	BTFSC GOTO	FLAG,1 PROCESS	_CODE	Example	HERE	CALL	THERE			
	TRUE	•				Before II	nstruction				
		•				After Ins	_	Address HE	RE		
	Before In	struction				711101 1110		Address TH	IERE		
	After Inst	PC = a truction if FLAG<1: PC =	address F				TOS = A	Address HE	RE+1		
		if FLAG<1: PC =	> = 1, address TI	RUE							

### 17.2 DC Characteristics: PIC16LC72-04 (Commercial, Industrial)

DC CHA	ARACTERISTICS			ard Ope	•	•	itions (unless otherwise stated)  0°C ≤ TA ≤ +85°C for industrial and  C ≤ TA ≤ +70°C for commercial
Param No.	Characteristic	Sym	Min	Тур†	Max	Units	Conditions
D001	Supply Voltage	VDD	2.5	-	6.0	٧	LP, XT, RC osc configuration (DC - 4 MHz)
D002*	RAM Data Retention Voltage (Note 1)	VDR	-	1.5	-	V	
D003	VDD start voltage to ensure internal Power-on Reset signal	VPOR	-	Vss	-	V	See section on Power-on Reset for details
D004*	VDD rise rate to ensure internal Power-on Reset signal	SVDD	0.05	-	-	V/ms	See section on Power-on Reset for details
D005	Brown-out Reset Voltage	Bvdd	3.7	4.0	4.3	٧	BODEN bit in configuration word enabled
D010	Supply Current (Note 2,5)	IDD	-	2.0	3.8	mA	XT, RC osc configuration FOSC = 4 MHz, VDD = 3.0V (Note 4)
D010A			-	22.5	48	μΑ	LP osc configuration Fosc = 32 kHz, VDD = 3.0V, WDT disabled
D015*	Brown-out Reset Current (Note 6)	Δlbor	-	350	425	μΑ	BOR enabled VDD = 5.0V
D020	Power-down Current	IPD	-	7.5	30	μΑ	VDD = 3.0V, WDT enabled, -40°C to +85°C
D021	(Note 3,5)		-	0.9	5	μΑ	VDD = 3.0V, WDT disabled, 0°C to +70°C
D021A			-	0.9	5	μΑ	VDD = 3.0V, WDT disabled, -40°C to +85°C
D023*	Brown-out Reset Current (Note 6)	$\Delta IBOR$	-	350	425	μΑ	BOR enabled VDD = 5.0V

- \* These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.
- Note 1: This is the limit to which VDD can be lowered without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.
    - The test conditions for all IDD measurements in active operation mode are:
    - OSC1 = external square wave, from rail to rail; all I/O pins tristated, pulled to VDD
    - $\overline{MCLR}$  = VDD; WDT enabled/disabled as specified.
  - 3: The power-down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VbD and Vss.
  - 4: For RC osc configuration, current through Rext is not included. The current through the resistor can be estimated by the formula Ir = VDD/2Rext (mA) with Rext in kOhm.
  - 5: Timer1 oscillator (when enabled) adds approximately  $20\,\mu\text{A}$  to the specification. This value is from characterization and is for design guidance only. This is not tested.
  - 6: The  $\Delta$  current is the additional current consumed when this peripheral is enabled. This current should be added to the base IDD or IPD measurement.

Standard Operating Conditions (unless otherwise stated)

Operating temperature  $-40^{\circ}\text{C} \leq \text{TA} \leq +125^{\circ}\text{C}$  for extended,

 $-40^{\circ}$ C  $\leq$  TA  $\leq$  +85°C for industrial and

 $0^{\circ}C \leq TA \leq +70^{\circ}C$  for commercial

Operating voltage VDD range as described in DC spec Section 17.1

and Section 17.2.

Param	Characteristic	Sym	Min	Тур	Max	Units	Conditions
No.				†			
	Output High Voltage						
D090	I/O ports (Note 3)	Voн	VDD - 0.7	-	-	V	IOH = $-3.0$ mA, VDD = $4.5$ V, $-40$ °C to $+85$ °C
D090A			VDD - 0.7	-	-	V	IOH = $-2.5$ mA, VDD = $4.5$ V, $-40$ °C to $+125$ °C
D092	OSC2/CLKOUT (RC osc config)		VDD - 0.7	-	-	V	IOH = -1.3 mA, VDD = $4.5V$ , $-40^{\circ}$ C to $+85^{\circ}$ C
D092A			VDD - 0.7	-	-	V	IOH = -1.0 mA, VDD = $4.5V$ , $-40^{\circ}$ C to $+125^{\circ}$ C
D150*	Open-Drain High Voltage	Vod	-	-	14	V	RA4 pin
	Capacitive Loading Specs on Output Pins						
D100	OSC2 pin	Cosc <sub>2</sub>	-	-	15	pF	In XT, HS and LP modes when external clock is used to drive OSC1.
D101	All I/O pins and OSC2 (in RC mode)	Cio	-	-	50	pF	
D102	SCL, SDA in I <sup>2</sup> C mode	Св	-	-	400	pF	

<sup>\*</sup> These parameters are characterized but not tested.

DC CHARACTERISTICS

- Note 1: In RC oscillator configuration, the OSC1/CLKIN pin is a Schmitt trigger input. It is not recommended that the PIC16C7X be driven with external clock in RC mode.
  - 2: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltages.
  - 3: Negative current is defined as current sourced by the pin.

<sup>†</sup> Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 18-9: I<sup>2</sup>C BUS START/STOP BITS TIMING

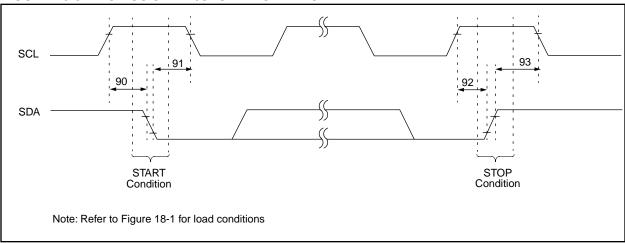
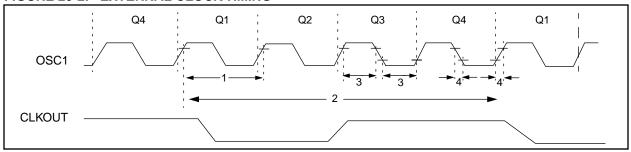


TABLE 18-9: I<sup>2</sup>C BUS START/STOP BITS REQUIREMENTS

Parameter No.	Sym	Characteristic		Min	Тур	Max	Units	Conditions	
90	Tsu:sta	START condition	100 kHz mode	4700	_	_	ns	Only relevant for repeated START	
		Setup time	400 kHz mode	600	_	_	115	condition	
91	THD:STA	START condition	100 kHz mode	4000	_	_	nc	After this period the first clock	
		Hold time	400 kHz mode	600	_	_	ns	pulse is generated	
92	Tsu:sto	STOP condition	100 kHz mode	4700	_	_	ns		
		Setup time	400 kHz mode	600	_	_	115		
93	THD:STO	STOP condition	100 kHz mode	4000	_	_	ns		
		Hold time	400 kHz mode	600	_	_	115		

### 20.5 <u>Timing Diagrams and Specifications</u>

### FIGURE 20-2: EXTERNAL CLOCK TIMING



### TABLE 20-2: EXTERNAL CLOCK TIMING REQUIREMENTS

Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions
	Fosc	External CLKIN Frequency	DC		4	MHz	XT and RC osc mode
		(Note 1)	DC	_	4	MHz	HS osc mode (-04)
			DC	_	10	MHz	HS osc mode (-10)
			DC	_	20	MHz	HS osc mode (-20)
			DC	_	200	kHz	LP osc mode
		Oscillator Frequency	DC	_	4	MHz	RC osc mode
		(Note 1)	0.1	_	4	MHz	XT osc mode
			4	_	20	MHz	HS osc mode
			5	1	200	kHz	LP osc mode
1	Tosc	External CLKIN Period	250	_	_	ns	XT and RC osc mode
		(Note 1)	250	_	_	ns	HS osc mode (-04)
			100	_	_	ns	HS osc mode (-10)
			50	_	_	ns	HS osc mode (-20)
			5	_	_	μs	LP osc mode
		Oscillator Period	250		_	ns	RC osc mode
		(Note 1)	250	_	10,000	ns	XT osc mode
			250	_	250	ns	HS osc mode (-04)
			100	_	250	ns	HS osc mode (-10)
							HS osc mode (-20)
			50	_	250	ns	
			5		_	μs	LP osc mode
2	Tcy	Instruction Cycle Time (Note 1)	200	Tcy	DC	ns	Tcy = 4/Fosc
3	TosL,	External Clock in (OSC1) High or	100	_	_	ns	XT oscillator
	TosH	Low Time	2.5	_	_	μs	LP oscillator
			15		_	ns	HS oscillator
4	TosR,	External Clock in (OSC1) Rise or	_	_	25	ns	XT oscillator
	TosF	Fall Time	-	_	50	ns	LP oscillator
+ Dots		column is at EV 25°C unless athemais	_		15	ns	HS oscillator

<sup>†</sup> Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Instruction cycle period (TCY) equals four times the input oscillator time-base period. All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. All devices are tested to operate at "min." values with an external clock applied to the OSC1/CLKIN pin. When an external clock input is used, the "Max." cycle time limit is "DC" (no clock) for all devices.

# PIC16C7X

## **Applicable Devices** | 72 | 73 | 73A | 74 | 74A | 76 | 77 |

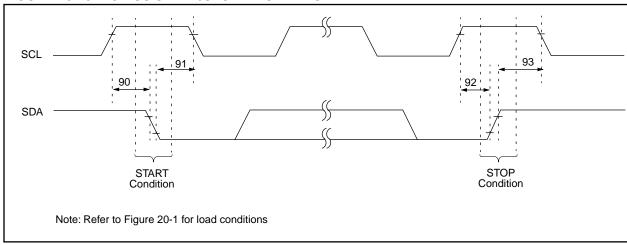
### TABLE 20-8: SPI MODE REQUIREMENTS

Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions
70*	TssL2scH, TssL2scL	SS↓ to SCK↓ or SCK↑ input	Tcy	_	_	ns	
71*	TscH	SCK input high time (slave mode)	Tcy + 20	_	_	ns	
72*	TscL	SCK input low time (slave mode)	Tcy + 20	_	_	ns	
73*	TdiV2scH, TdiV2scL	Setup time of SDI data input to SCK edge	100	_	_	ns	
74*	TscH2diL, TscL2diL	Hold time of SDI data input to SCK edge	100	_	_	ns	
75*	TdoR	SDO data output rise time	_	10	25	ns	
76*	TdoF	SDO data output fall time	_	10	25	ns	
77*	TssH2doZ	SS↑ to SDO output hi-impedance	10	_	50	ns	
78*	TscR	SCK output rise time (master mode)	_	10	25	ns	
79*	TscF	SCK output fall time (master mode)	_	10	25	ns	
80*	TscH2doV, TscL2doV	SDO data output valid after SCK edge	_	_	50	ns	
81*	TdoV2scH, TdoV2scL	SDO data output setup to SCK edge	Tcy	_	_	ns	
82*	TssL2doV	SDO data output valid after <del>SS</del> ↓ edge	_	_	50	ns	
83*	TscH2ssH, TscL2ssH	SS ↑ after SCK edge	1.5Tcy + 40	_	_	ns	

<sup>\*</sup> These parameters are characterized but not tested.

<sup>†</sup> Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

### FIGURE 20-13: I<sup>2</sup>C BUS START/STOP BITS TIMING



## TABLE 20-9: I<sup>2</sup>C BUS START/STOP BITS REQUIREMENTS

Parameter No.	Sym	Characteristic		Min	Тур	Max	Units	Conditions
90	Tsu:sta	START condition	100 kHz mode	4700	_	_	ns	Only relevant for repeated START
		Setup time	400 kHz mode	600	_	_	110	condition
91	THD:STA	START condition	100 kHz mode	4000	_	_	ns	After this period the first clock
		Hold time	400 kHz mode	600	_	_	113	pulse is generated
92	Tsu:sto	STOP condition	100 kHz mode	4700	_	_	ns	
		Setup time	400 kHz mode	600	_	_	113	
93	THD:STO	STOP condition	100 kHz mode	4000	_	_	ns	
		Hold time	400 kHz mode	600	_	_	115	

# PIC16C7X

### **Applicable Devices** 72 73 73A 74 74A 76 77

### FIGURE 20-14: I<sup>2</sup>C BUS DATA TIMING

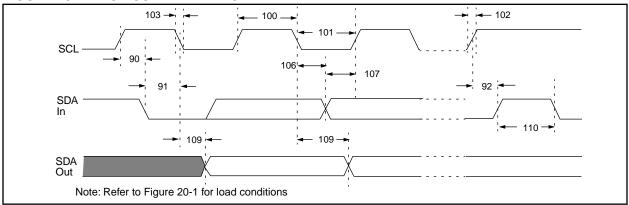


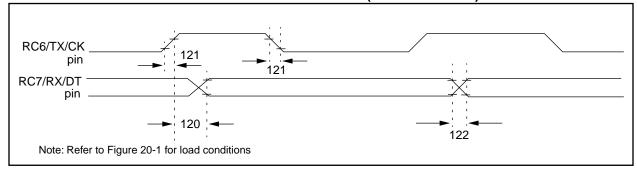
TABLE 20-10: I<sup>2</sup>C BUS DATA REQUIREMENTS

Parameter No.	Sym	Characteristic		Min	Max	Units	Conditions
100	THIGH	Clock high time	100 kHz mode	4.0	_	μs	Device must operate at a minimum of 1.5 MHz
			400 kHz mode	0.6	_	μs	Device must operate at a minimum of 10 MHz
			SSP Module	1.5TcY	_		
101	TLOW	Clock low time	100 kHz mode	4.7	_	μs	Device must operate at a minimum of 1.5 MHz
			400 kHz mode	1.3	_	μs	Device must operate at a minimum of 10 MHz
			SSP Module	1.5TcY	_		
102	Tr	SDA and SCL rise	100 kHz mode	_	1000	ns	
		time	400 kHz mode	20 + 0.1Cb	300	ns	Cb is specified to be from 10 to 400 pF
103	TF	SDA and SCL fall time	100 kHz mode	_	300	ns	
			400 kHz mode	20 + 0.1Cb	300	ns	Cb is specified to be from 10 to 400 pF
90	Tsu:sta	START condition	100 kHz mode	4.7	_	μs	Only relevant for repeated
		setup time	400 kHz mode	0.6	_	μs	START condition
91	THD:STA	START condition hold	100 kHz mode	4.0	_	μs	After this period the first clock
		time	400 kHz mode	0.6	_	μs	pulse is generated
106	THD:DAT	Data input hold time	100 kHz mode	0	_	ns	
			400 kHz mode	0	0.9	μs	
107	TSU:DAT	Data input setup time	100 kHz mode	250	_	ns	Note 2
			400 kHz mode	100	_	ns	
92	Tsu:sto	STOP condition setup	100 kHz mode	4.7	_	μs	
		time	400 kHz mode	0.6	_	μs	
109	TAA	Output valid from	100 kHz mode	_	3500	ns	Note 1
		clock	400 kHz mode		_	ns	
110	TBUF	Bus free time	100 kHz mode	4.7	_	μs	Time the bus must be free
			400 kHz mode	1.3	_	μs	before a new transmission can start
	Cb	Bus capacitive loading			400	pF	

Note 1: As a transmitter, the device must provide this internal minimum delay time to bridge the undefined region (min. 300 ns) of the falling edge of SCL to avoid unintended generation of START or STOP conditions.

<sup>2:</sup> A fast-mode (400 kHz) I²C-bus device can be used in a standard-mode (100 kHz) I²C-bus system, but the requirement tsu;DAT ≥ 250 ns must then be met. This will automatically be the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line TR max.+tsu;DAT = 1000 + 250 = 1250 ns (according to the standard-mode I²C bus specification) before the SCL line is released.

### FIGURE 20-15: USART SYNCHRONOUS TRANSMISSION (MASTER/SLAVE) TIMING

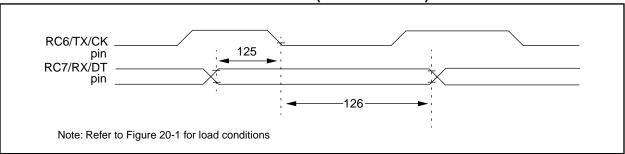


### TABLE 20-11: USART SYNCHRONOUS TRANSMISSION REQUIREMENTS

Param No.	Sym	Characteristic		Min	Тур†	Max	Units	Conditions
120	TckH2dtV	SYNC XMIT (MASTER & SLAVE)	PIC16 <b>C</b> 76/77	_	_	80	ns	
		Clock high to data out valid	PIC16 <b>LC</b> 76/77	_	_	100	ns	
121	Tckrf	Clock out rise time and fall time (Master Mode)	PIC16 <b>C</b> 76/77	_	_	45	ns	
			PIC16 <b>LC</b> 76/77	_	_	50	ns	
122	Tdtrf	Data out rise time and fall time	PIC16 <b>C</b> 76/77	_	_	45	ns	
			PIC16 <b>LC</b> 76/77	_	_	50	ns	

<sup>†:</sup> Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

### FIGURE 20-16: USART SYNCHRONOUS RECEIVE (MASTER/SLAVE) TIMING



### TABLE 20-12: USART SYNCHRONOUS RECEIVE REQUIREMENTS

Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions
125	TdtV2ckL	SYNC RCV (MASTER & SLAVE) Data setup before CK ↓ (DT setup time)	15	_	_	ns	
126	TckL2dtl	Data hold after CK ↓ (DT hold time)	15	_	_	ns	

<sup>†:</sup> Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

**Applicable Devices** | 72 | 73 | 73A | 74 | 74A | 76 | 77

FIGURE 21-22: TYPICAL XTAL STARTUP TIME vs. VDD (LP MODE, 25°C)

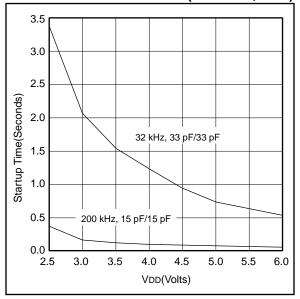


FIGURE 21-23: TYPICAL XTAL STARTUP TIME vs. VDD (HS MODE, 25°C)

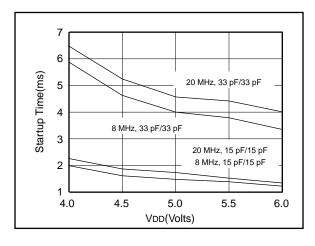


FIGURE 21-24: TYPICAL XTAL STARTUP TIME vs. VDD (XT MODE, 25°C)

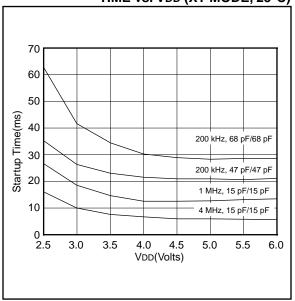
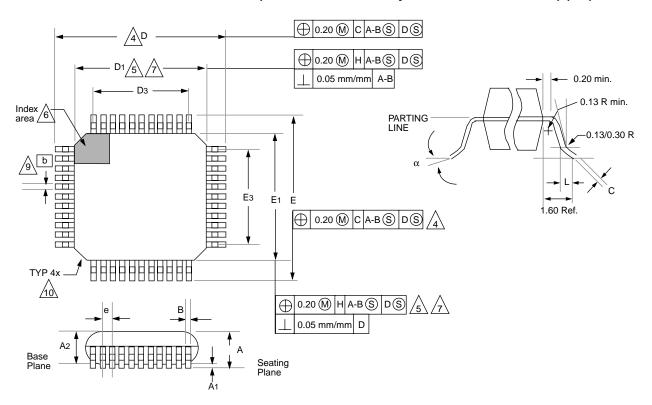


TABLE 21-2: CAPACITOR SELECTION FOR CRYSTAL OSCILLATORS

Osc Type	Crystal Freq	Cap. Range C1	Cap. Range C2
LP	32 kHz	33 pF	33 pF
	200 kHz	15 pF	15 pF
XT	200 kHz	47-68 pF	47-68 pF
	1 MHz	15 pF	15 pF
	4 MHz	15 pF	15 pF
HS	4 MHz	15 pF	15 pF
	8 MHz	15-33 pF	15-33 pF
	20 MHz	15-33 pF	15-33 pF
Crystals Used			
32 kHz	Epson C-00	01R32.768K-A	± 20 PPM
200 kHz	STD XTL 2	00.000KHz	± 20 PPM
1 MHz	ECS ECS-	± 50 PPM	
4 MHz	ECS ECS-4	± 50 PPM	
8 MHz	EPSON CA	± 30 PPM	
20 MHz	EPSON CA	x-301 20.000M-C	± 30 PPM

### 22.8 44-Lead Plastic Surface Mount (MQFP 10x10 mm Body 1.6/0.15 mm Lead Form) (PQ)



	Package Group: Plastic MQFP							
		Millimeters		Inches				
Symbol	Min	Max	Notes	Min	Max	Notes		
α	0°	7°		0°	7°			
Α	2.000	2.350		0.078	0.093			
A1	0.050	0.250		0.002	0.010			
A2	1.950	2.100		0.768	0.083			
b	0.300	0.450	Typical	0.011	0.018	Typical		
С	0.150	0.180		0.006	0.007			
D	12.950	13.450		0.510	0.530			
D1	9.900	10.100		0.390	0.398			
D3	8.000	8.000	Reference	0.315	0.315	Reference		
E	12.950	13.450		0.510	0.530			
E1	9.900	10.100		0.390	0.398			
E3	8.000	8.000	Reference	0.315	0.315	Reference		
е	0.800	0.800		0.031	0.032			
L	0.730	1.030		0.028	0.041			
N	44	44		44	44			
СР	0.102	_		0.004	_			